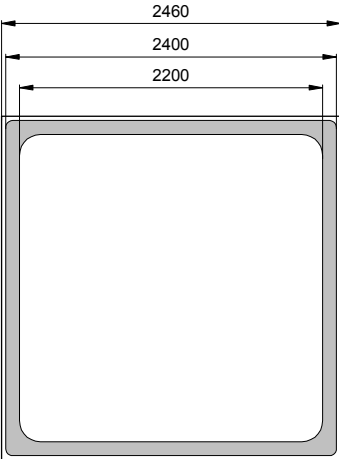


| Wavelength range | Type | Technology | Electrodes |
|------------------|------------------|------------|--------------|
| UV-blue-green | Schottky Contact | GaP | P (anode) up |

| | | |
|---|---|--|
|  | typ. dimensions (μm) | |
| | <u>typ. thickness</u> 300 μm <u>anode</u> bond gold 1.0 μm <u>cathode</u> gold alloy, 0.5 μm | Description High spectral sensitivity in the blue and ultraviolet range, low dark currents, low cost chip with high degradation stability Applications special light barriers, sensors for flame control and automation |

Miscellaneous Parameters

$T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified

| Parameter | Test conditions | Symbol | Value | Unit |
|----------------------------------|-----------------|------------|-------------|--------------------|
| Active area | | A | 4.8 | mm ² |
| Temperature coefficient of I_D | | $T_C(I_D)$ | 7.0 | %/K |
| Operating temperature range | | T_{amb} | -40 to +125 | $^{\circ}\text{C}$ |
| Storage temperature range | | T_{stg} | -40 to +125 | $^{\circ}\text{C}$ |

Optical and Electrical Characteristics

$T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified

| Parameter | Test conditions | Symbol | Min | Typ | Max | Unit |
|---------------------------------------|---------------------------|--------------------------------|------|-----------------------|-----|-----------------------------|
| Dark current | $V_R = 5\text{ V}$ | I_D | | 15 | 40 | pA |
| Peak sensitivity wavelength | $V_R = 0\text{ V}$ | λ_p | | 440 | | nm |
| Responsivity at λ_p^* | $V_R = 0\text{ V}$ | S_λ | | 0.17 | | A/W |
| Sensitivity range at 1% | $V_R = 0\text{ V}$ | $\lambda_{min}, \lambda_{max}$ | <110 | | 570 | nm |
| Spectral bandwidth at 50% | $V_R = 0\text{ V}$ | $\Delta\lambda_{0.5}$ | | 180 | | nm |
| Shunt resistance | $V_R = 10\text{ mV}$ | R_D | 80 | 100 | | GΩ |
| Noise equivalent power | $\lambda = 440\text{ nm}$ | NEP | | 1.3×10^{-14} | | $\text{W}/\sqrt{\text{Hz}}$ |
| Junction capacitance | $V_R = 0\text{ V}$ | C_J | | 1000 | | pF |
| Switching time ($R_L = 50\ \Omega$) | $V_R = 5\text{ V}$ | t_r, t_f | | 1/60 | | ns |

*Measured on bare chip on TO-18 header

Labeling

| Type | Typ. I_D [pA] | Typ. S_λ [A/W] | Lot N° | Quantity |
|-------------|-----------------|------------------------|--------|----------|
| EPC-440-2.5 | | | | |

Packing: Chips on adhesive film with wire-bond side on top

Note: All measurements carried out with *EPIGAP* equipment

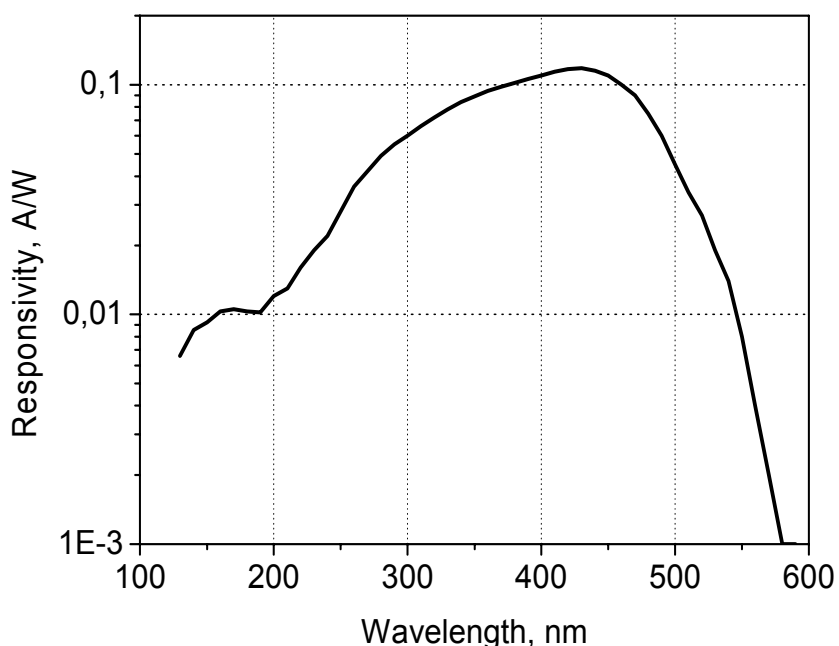
We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer.

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Typical responsivity spectrum



Handling instructions of UV-photodiode dies on blue tape (Nitto's SWT 20)

EPIGAP's UV-photodiode dies are delivered on adhesive blue tape rings. For mounting these dies have to be removed from the tape. They are sensitive to surface touching so they should only be handled from the side. To minimize mechanical stress or chipping use only plastic tweezers or die collets for picking. Because larger dies are stronger stuck to the tape use one round point needle of about 1mm diameter or several pin point needles from the rear side to loosen the dies before picking.